NSN 5961-01-467-6714

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-467-6714 **Inclosure Material:** Glass **End Application:** E/ifscm 04713 **Mounting Facility Quantity: Mounting Method:** Terminal **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 32.0 working peak reverse voltage **Current Rating Per Characteristic:** 300.00 amperes source cutoff current absolute **Maximum Operating Tempurature Per Measurement Point:** -55.0 degrees celsius case and 150.0 degrees celsius case **Special Features:** Unidirectional transient suppressor **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: A110a0